



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT

FAST SWITCHING DIODE ARRAY

VOLTAGE 75 Volts CURRENT 215 mAmpere

BAV99BDWGP-A

APPLICATION

- * Ultra high speed switching
- * For general purpose switching application

FEATURE

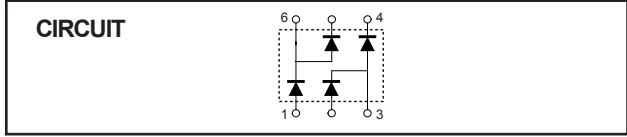
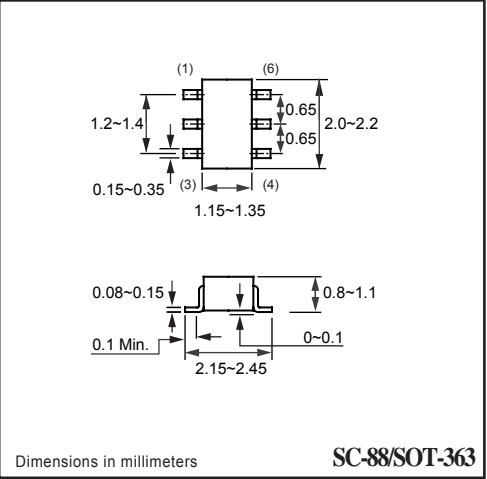
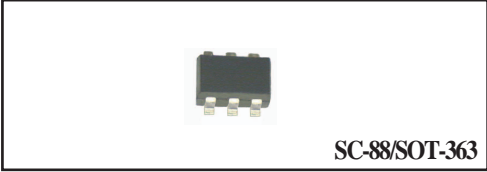
- * Small surface mounting type. (SC-88/SOT-363)
- * High speed. (T_{RR}=1.5nSec Typ.)
- * Suitable for high packing density.
- * Maximum total power dissipation is 300mW.
- * Peak forward current is 350mA.
- * Moistur sensitivity:Level 1 per J-STD-020C

CONSTRUCTION

- * Silicon epitaxial planar

MARKING

DN



MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	BAV99BDWGP-A	UNITS
Maximum Non-Repetitive Peak Reverse Voltage	V _{RM}	100	Volts
Maximum RMS Voltage	V _{RMS}	53	Volts
Maximum Repetitive Peak Reverse and DC Blocking Voltage	V _{RRM, VDC}	75	Volts
Maximum Average Forward Rectified Current	I _O	215	mAmps
Non-Repetitive Peak Forward Surge Current	@t=1.0uSec	2.0	Amps
	@t=1.0Sec	1.0	
Typical Junction Capacitance between Terminal (Note 1)	C _J	2.0	pF
Maximum Reverse Recovery Time (Note 2)	T _{RR}	4.0	nSec
Thermal Resistance Junction to Ambient (Note 3)	R _{θJA}	625	°C/W
Maximum Operating and Storage Temperature Range	T _{J, TSTG}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	BAV99BDWGP-A	UNITS
Maximum Instantaneous Forward Voltage	V _F	@I _F =1.0mA	0.715
		@I _F =10mA	0.855
		@I _F =50mA	1.00
		@I _F =150mA	1.25
Maximum Average Reverse Current	I _R	@V _R =20V	25
		@V _R =75V	2.5
		@V _R =25V, T _J =150°C	30
		@V _R =75V, T _J =150°C	50

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 0 volts.
 2. Measured at applied forward current of 10mA and reverse current of 10mA.
 3. Device mounted on FR-4 by 1 inch X 0.85 inch X 0.062 inch
 4. ESD sensitive product handling required.

RATING CHARACTERISTIC CURVES (BAV99BDWGP-A)

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

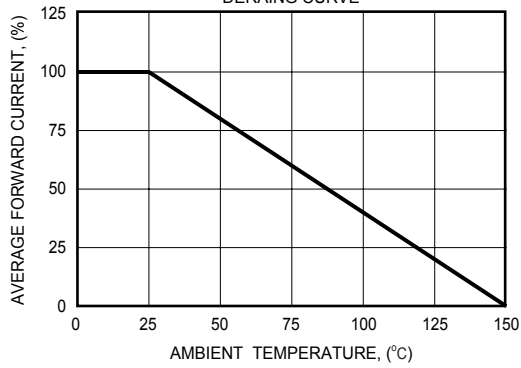


FIG. 2 - FORWARD CHARACTERISTICS

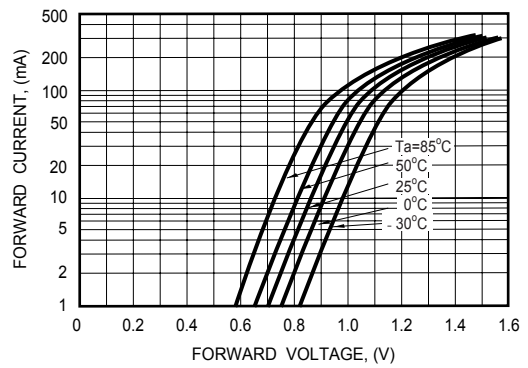


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

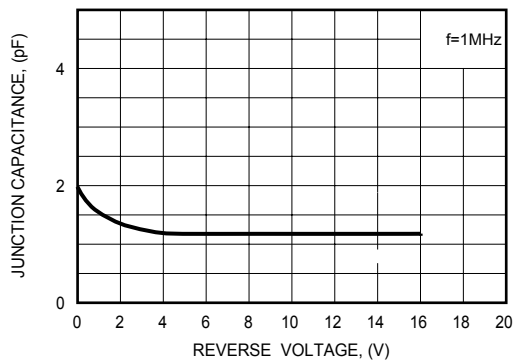


FIG. 4 - REVERSE CHARACTERISTICS

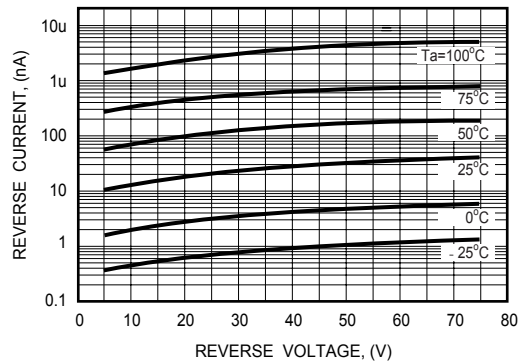


FIG. 5 - REVERSE RECOVERY TIME

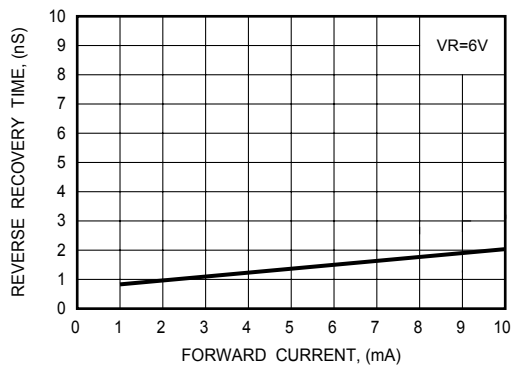


FIG. 6 - REVERSE RECOVERY TIME MEASUREMENT CIRCUIT

